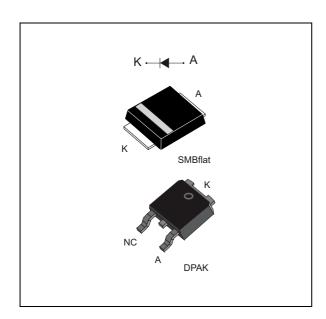
STPS4S200



Power Schottky rectifier

Datasheet - production data



Features

- · Negligible switching losses
- · High junction temperature capability
- Very small conduction losses
- · Low leakage current
- Avalanche rated
- ECOPACK[®] compliant component (SMBflat)
- T_i = -40 °C minimum operating

Description

This device is a 200 V Schottky rectifier suited for switch mode power supplies and high frequency DC to DC converters.

Packaged in DPAK and SMBflat, this device is especially intended for use in low voltage, high frequency inverters, freewheeling and polarity protection. Also ideal for all LED lighting applications.

Table 1. Device summary

Symbol	Value
I _{F(AV)}	4 A
V _{RRM}	200 V
V _F (typ)	0.64 V
T _j (max)	175 °C

Characteristics STPS4S200

1 Characteristics

Table 2. Absolute ratings (limiting values at 25 °C, unless otherwise specified)

Symbol	Parameter	Value	Unit	
V _{RRM}	Repetitive peak reverse voltage	200	V	
I _{F(RMS)}	Forward rms current		10	А
	Average forward current, $\delta = 0.5$, square	DPAK, T _c = 160 °C	4	А
lF(AV)	wave	SMBflat, T _L = 125 °C	4	
I _{FSM}	Surge non repetitive forward current	250	А	
T _{stg}	Storage temperature range	-65 to +175	°C	
Tj	Operating junction temperature ⁽¹⁾	-40 to +175	°C	

^{1.} $\frac{dPtot}{dTj} < \frac{1}{Rth(j-a)}$ condition to avoid thermal runaway for a diode on its own heatsink

Table 3. Thermal parameters

Symbol	Parameter	Value	Unit
R _{th(j-c)}	Junction to case, DPAK	3.2	°C/W
R _{th(j-l)}	Junction to lead, SMBflat	15	C/VV

When the two diodes 1 and 2 are used simultaneously:

 $\Delta T_{j}(diode1) = P(diode1) \times R_{th(j-c)}(per\ diode) + P(diode2) \times R_{th(c)}$

Table 4. Static electrical characteristics

Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
I _R ⁽¹⁾	L (1) Reverse leakage current		$V_R = V_{RRM}$			5	μΑ
I _R ⁽¹⁾ Reverse leakage current	T _j = 125 °C			0.7	2.5	mA	
V _F ⁽²⁾ Forward voltage drop		T _j = 25 °C	I _E = 4 A			0.87	V
		T _j = 125 °C	1F - 4 A		0.64	0.71	V

^{1.} Pulse test: $t_p = 5$ ms, $\delta < 2\%$

To evaluate the conduction losses use the following equation:

$$P = 0.63 \times I_{F(AV)} + 0.020 I_{F^{2}(RMS)}$$

^{2.} Pulse test: $t_p = 380 \,\mu s$, $\delta < 2\%$

STPS4S200 **Characteristics**

Figure 1. Average forward power dissipation versus average forward current

 $P_{F(AV)}(W)$ 3.5 δ = 0.05 $\delta = 0.1 \quad \delta = 0.2$ 3.0 2.5 2.0 1.5 1.0 0.5 $I_{\mathsf{F}(\mathsf{AV})}(\mathsf{A})$ 0.0 1.0 1.5 2.0 2.5 3.0 4.0

Figure 2. Average forward current versus ambient temperature (δ = 0.5)

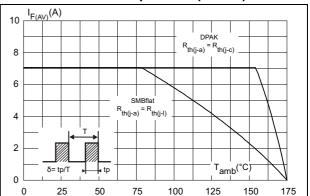
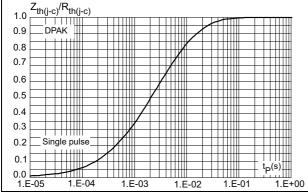


Figure 3. Relative variation of thermal impedance, junction to case, versus pulse duration (DPAK)

Figure 4. Relative variation of thermal impedance, junction to lead versus pulse duration (SMBflat) $Z_{th(j-l)}/R_{th(j-l)}$ 1.0



0.9 SMBflat 0.8 0.7 0.6 0.5 0.4 0.3 Single pulse 0.2 0.1 t_P(s) 0.0 1.E-04 1.E-03 1.E-02 1.E-01 1.E+00 1.E+01

Figure 5. Reverse leakage current versus reverse voltage applied (typical values)

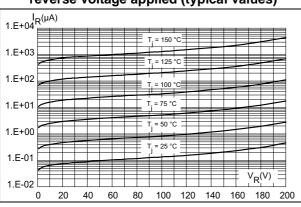
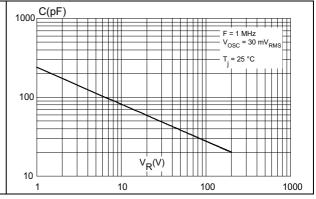
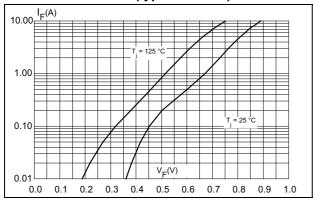


Figure 6. Junction capacitance versus reverse voltage applied (typical values)



Characteristics STPS4S200

Figure 7. Forward voltage drop versus forward Figure 8. Forward voltage drop versus forward current (typical values) current (maximum values)



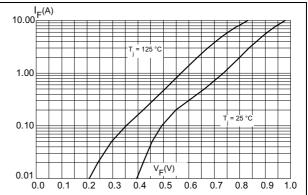
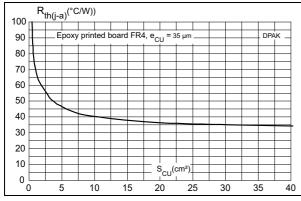
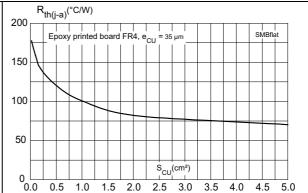


Figure 9. Thermal resistance junction to ambient versus copper surface under tab (typical values)

Figure 10. Thermal resistance junction to ambient versus copper surface under each lead (typical values)





2 Package information

- Epoxy meets UL94,V0
- Lead-free package
- · Band indicates cathode

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK[®] is an ST trademark.

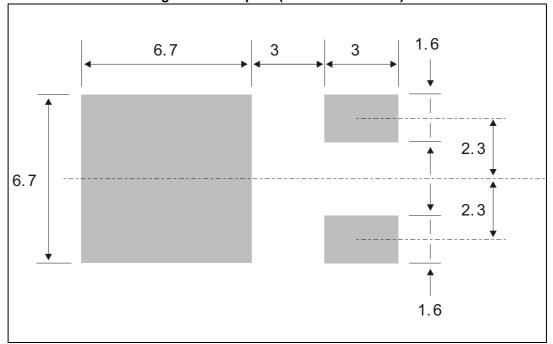
Figure 11. DPAK dimension definitions Ė B₂ C2 L2 D R В С A2 0.60 min.

Package information STPS4S200

Table 5. DPAK dimension values

	Dimensions					
Ref.		Millimeters		Inches		
	Min.	Тур.	Max.	Min.	Тур.	Max.
А	2.20		2.40	0.086		0.094
A1	0.90		1.10	0.035		0.043
A2	0.03		0.23	0.001		0.009
В	0.64		0.90	0.025		0.035
B2	5.20		5.40	0.204		0.212
С	0.45		0.60	0.017		0.023
C2	0.48		0.60	0.018		0.023
D	6.00		6.20	0.236		0.244
Е	6.40		6.60	0.251		0.259
G	4.40		4.60	0.173		0.181
Н	9.35		10.10	0.368		0.397
L2		0.80 typ.			0.031 typ.	
L4	0.60		1.00	0.023		0.039
V2	0°		8°	0°		8°

Figure 12. Footprint (dimensions in mm)



STPS4S200 Package information

E E1 L2x L2x L12x

Figure 13. SMBflat dimensions definitions

Table 6. SMBflat dimension values

	Dimensions					
Ref.		Millimeters				
	Min.	Тур.	Max.	Min.	Тур.	Max.
Α	0.90		1.10	0.035		0.043
b	1.95		2.20	0.077		0.087
С	0.15		0.40	0.006		0.016
D	3.30		3.95	0.130		0.155
E	5.10		5.60	0.200		0.220
E1	4.05		4.60	0.159		0.181
L	0.75		1.50	0.029		0.059
L1		0.40			0.016	
L2		0.60			0.024	

Package information STPS4S200

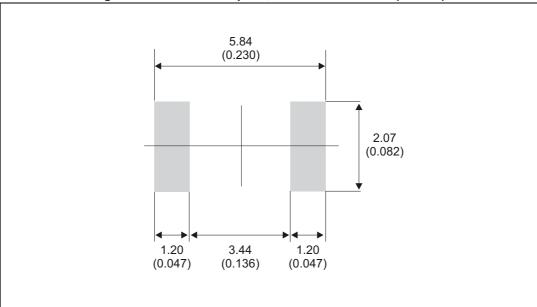


Figure 14. SMBflat footprint, dimensions in mm (inches)

3 Ordering information

Table 7. Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
STPS4S200B-TR	S4 200B	DPAK	0.3 g	2500	Tape and reel
STPS4S200UF	FG42	SMBflat	0.050 g	5000	Tape and reel

4 Revision history

Table 8. Document revision history

Date	Revision	Changes
17-Oct-2014	1	First release.

IMPORTANT NOTICE - PLEASE READ CAREFULLY

STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, enhancements, modifications, and improvements to ST products and/or to this document at any time without notice. Purchasers should obtain the latest relevant information on ST products before placing orders. ST products are sold pursuant to ST's terms and conditions of sale in place at the time of order acknowledgement.

Purchasers are solely responsible for the choice, selection, and use of ST products and ST assumes no liability for application assistance or the design of Purchasers' products.

No license, express or implied, to any intellectual property right is granted by ST herein.

10/10

Resale of ST products with provisions different from the information set forth herein shall void any warranty granted by ST for such product.

ST and the ST logo are trademarks of ST. All other product or service names are the property of their respective owners.

Information in this document supersedes and replaces information previously supplied in any prior versions of this document.

© 2014 STMicroelectronics - All rights reserved

DocID027021 Rev1